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<b>Session Title:</b>	<b>[MoB3] Optical Characterization</b>
<b>Session Date:</b>	<b>July 13 (Mon.), 2026</b>
<b>Session Time:</b>	<b>16:05-17:50</b>
<b>Session Room:</b>	<b>Room B (Baekrok Hall B-2, 1F)</b>
<b>Session Chairs</b>	

<b>[MoB3-1] [Invited]</b>	<b>16:05-16:35</b>
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**Optical In-Situ Metrology and MOVPE: Versatile Toolbox for Laser Device Growth**

A. Maaßdorf, M. Brendel, S. Breuer, and M. Weyers, Ferdinand-Braun-Institut, Germany

<b>[MoB3-2]</b>	<b>16:35-16:50</b>
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**Composition-Dependent Raman Anisotropy in MOVPE-Grown Non-Polar (11-20)  $Al_xGa_{1-x}N$**

A Azizur Rahman<sup>1</sup>, Eeshika Suresh<sup>1,2</sup>, Maheshwar Gokhale<sup>1</sup>, Amit P Shah<sup>1</sup>, Kailash Rustagi<sup>1</sup>, and Arnab Bhattacharya<sup>1</sup>, <sup>1</sup>Tata Institute of Fundamental Research, India, <sup>2</sup>Amrita Vishwa Vidyapeetham, India

<b>[MoB3-3]</b>	<b>16:50-17:05</b>
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**Optical Response and Anisotropy in MOVPE-Grown Non-Polar  $Al_xGa_{1-x}N$ : Insights from Mueller Matrix Ellipsometry**

A Azizur Rahman<sup>1</sup>, Sanchali Datta<sup>1,2</sup>, Maheshwar Gokhale<sup>1</sup>, Amit P Shah<sup>1</sup>, and Arnab Bhattacharya<sup>1</sup>, <sup>1</sup>Tata Institute of Fundamental Research, India, <sup>2</sup>Tripura University, India

<b>[MoB3-4]</b>	<b>17:05-17:20</b>
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**Design and Evaluation of Hexagonal Silicon Germanium Multi Quantum Wells for Lasing**

M.M. Jansen-Zilles, R. Farina, R.S. Tiemeijer, W.H.J. Peeters, M.F. Schouten, V.T. van Lange, M.A. Verheijen, J.E.M. Haverkort, and E.P.A.M. Bakkers, Eindhoven University of Technology, Netherlands

<b>[MoB3-5]</b>	<b>17:20-17:35</b>
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**Temperature- and Wavelength-Dependent Photoluminescence Lifetimes in InGaN Quantum Wells with Varying Indium Compositions**

Ririka Yamagata<sup>1</sup>, Soma Hatanaka<sup>1</sup>, Soya Yamagishi<sup>1</sup>, Itsuki Shimbo<sup>1</sup>, Atsushi A. Yamaguchi<sup>1</sup>, Kazunori Iwamitsu<sup>2</sup>, and Shigetaka Tomiya<sup>2</sup>, <sup>1</sup>Kanazawa Institute of Technology, Japan, <sup>2</sup>Nara Institute of Science and Technology, Japan

<b>[MoB3-6]</b>	<b>17:35-17:50</b>
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**Functional-Form Analysis of Photoluminescence Decay in InGaN Quantum Wells**

Arata Suzaki<sup>1</sup>, Ririka Yamagata<sup>1</sup>, Itsuki Shimbo<sup>1</sup>, Atsushi A. Yamaguchi<sup>1</sup>, Daisuke Iida<sup>2</sup>, and Kazuhiro Ohkawa<sup>2</sup>, <sup>1</sup>Kanazawa Institute of Technology, Japan, <sup>2</sup>King Abdullah University of Science and Technology, Saudi Arabia